CPH6355

Power MOSFET –30V, 169mΩ, –3A, Single P-Channel

Features

- Low ON-Resistance
- 4V Drive
- Pb-Free, Halogen Free and RoHS Compliance

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	-30	V
Gate to Source Voltage	V _{GSS}	±20	V
Drain Current (DC)	ID	-3	А
Drain Current (Pulse) PW≤10μs, duty cycle≤1%	IDP	-12	А
Power Dissipation When mounted on ceramic substrate (1500mm ² \times 0.8mm)	PD	1.6	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

This product is designed to "ESD immunity < 200V*", so please take care when handling. * Machine Model

^ Machine Model

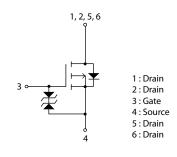
Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (1500mm ² \times 0.8mm)	R _{θJA}	78.1	°C/W



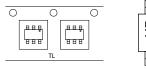
VDSS	R _{DS} (on) Max	ID Max
	169mΩ@ –10V	
-30V	276mΩ@ –4.5V	-3A
	313mΩ@ –4V	





Packing Type : TL

Marking





Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

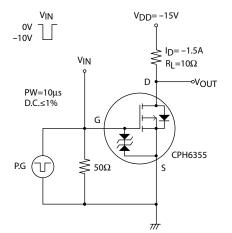
See detailed ordering and shipping information on page 5 of this data sheet.

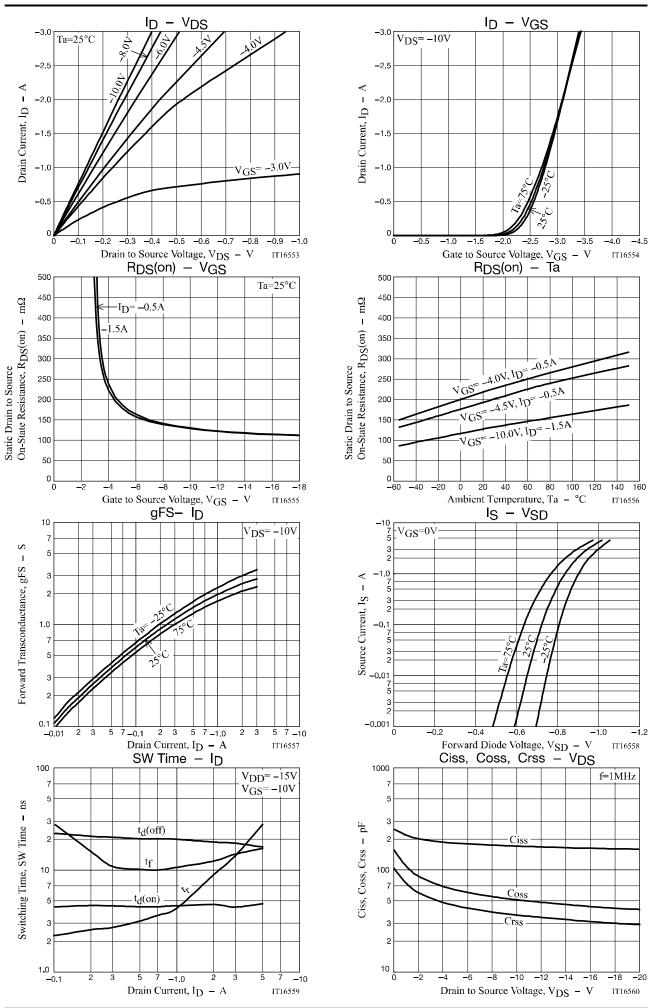
Electrical Characteristics at $Ta = 25^{\circ}C$

Parameter	Querra ha a l	Symbol Conditions	Value		11.1	
Parameter	Symbol		min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0V			-1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transconductance	9FS	V _{DS} =-10V, I _D =-1.5A		2.3		S
	R _{DS} (on)1	I _D =-1.5A, V _{GS} =-10V		130	169	mΩ
Static Drain to Source On-State Resistance	R _{DS} (on)2	I _D =-0.5A, V _{GS} =-4.5V		197	276	mΩ
	R _{DS} (on)3	I _D =-0.5A, V _{GS} =-4V		223	313	mΩ
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		172		pF
Output Capacitance	Coss			51		pF
Reverse Transfer Capacitance	Crss			36		pF
Turn-ON Delay Time	t _d (on)			4.6		ns
Rise Time	tr			6.6		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		19.4		ns
Fall Time	tf			11.4		ns
Total Gate Charge	Qg			3.9		nC
Gate to Source Charge	Qgs	V _{DS} =-15V, V _{GS} =-10V, I _D =-3A		0.6		nC
Gate to Drain "Miller" Charge	Qgd	1		0.8		nC
Forward Diode Voltage	V _{SD}	I _S =-3A, V _{GS} =0V		-0.95	-1.5	V

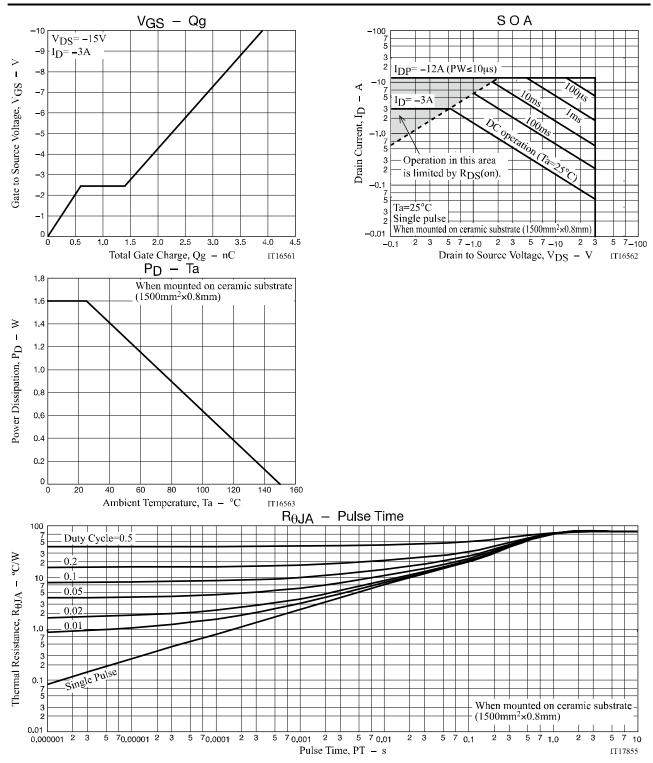
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit





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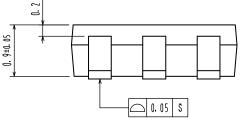


Package Dimensions

CPH6355-TL-H / CPH6355-TL-W

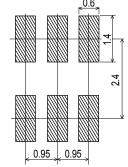
CPH6

CASE 318BD		0. 15 ^{+0. 1}
ISSUE O		"
Unit : mm		5±0.1
1 : Drain		
2 : Drain		
3 : Gate		
4 : Source		
5 : Drain		T_
6 : Drain		
		1 M A
	_PIN#1	Recommended
	0. 7	Soldering Footprin
		0.0



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ORDERING INFORMATION

Device	Package	Shipping	Note	
CPH6355-TL-H	CPH6, SC-74	3,000 pcs. / Tape & Reel	Pb-Free and	
CPH6355-TL-W	SOT-26, SOT-457	3,000 pcs. / Tape & Reef	Halogen Free	

*1:Lot indication

Note on usage : Since the CPH6355 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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